

# InGaP HBT 2.4 – 2.5 GHz Power Amplifier

### **PRODUCTION DATA SHEET**

## DESCRIPTION

IMPORTANT: For the most current data, consult MICROSEMI's website: http://www.microsemi.com

The LX5518 is a high gain and high power amplifier optimized 802.11b/g/n applications in the 2.4-2.5 the PA to help reduce BOM cost and GHz frequency range. The PA is PCB space for implementation of implemented as a three-stage monolithic power control in a typical wireless microwave integrated circuit (MMIC) system. active bias, on-chip input with matching, and output pre-matching.

The device is manufactured with an package (QFN) InGaP/GaAs Heterojunction Bipolar compact footprint, low profile, and Transistor (HBT) IC (MOCVD). It operates with a single LX5518 an ideal positive voltage supply of 3-5V, and 802.11b/g/n applications. provides a power gain of 30dB and an output power of +26dBm at 5V for 3% EVM in the 2.4-2.5GHz.

LX5518 also features an on-chip for power detector at the output port of

The LX5518 is available in a 16pin 3mm x 3mm quad flat no lead 3×3-16L). The process excellent thermal capability make the solution for

#### **KEY FEATURES**

**LX5518** 

- Advanced InGaP HBT
- 2.4-2.5GHz Operation
- Single-Polarity 3-5V Supply
- . Power Gain ~ 30 dB
- 26dBm @3%EVM,802.11g/5V
- 24dBm @3.5%EVM,80211g/3.3V
- 28dBm @CCK,802.11b/5V
- 27dBm @CCK,802.11b/3.3V
- 24.5% Efficiency @28dBm/5V
- Complete On-Chip Input Match
- Simple Output Match for Optimal EVM
- Temperature-Compensated On-Chip Output Power Detector with Wide Dynamic Range
- Small Footprint: 3x3mm<sup>2</sup>
- Low Profile: 0.9mm

#### APPLICATIONS

802.11b/g/n

**BLOCK DIAGRAM** Vc  $\cap$ RF RF Output Input Active Bias Network 🔿 Det Vref **3X3MM MLP PACKAGE** PACKAGE ORDER INFO Plastic QFN 3×3 LO 16 pin MSC RoHS Compliant / Pb-free 5518 LX5518LQ 936A Note: Available in Tape & Reel. Append the letters "TR" to the part number. (i.e. LX5518LQ-TR)



## INFORMATION

Thank you for your interest in Microsemi<sup>®</sup> Analog Mixed Signal products.

The full data sheet for this device contains proprietary information.

To obtain a copy, please contact your local Microsemi sales representative. The name of your local representative can be obtained at the following link <a href="http://www.microsemi.com/contact/contactfind.asp">http://www.microsemi.com/contact/contactfind.asp</a>

or

Contact us directly by sending an email to:

IPGdatasheets@microsemi.com

Be sure to specify the data sheet you are requesting and include your company name and contact information and or vcard.

We look forward to hearing from you.